

### Description

The AO4430 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

### **General Features**

 $V_{DS} = 30V I_D = 18A$  $R_{DS(ON)} < 6.5m\Omega @ V_{GS} = 10V$  $R_{DS(ON)} < 12m\Omega @ V_{GS} = 4.5V$ 

### Application

Battery protection

Load switch

Uninterruptible power supply

### Package Marking and Ordering Information

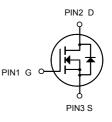
Product ID	Pack	Marking	Qty(PCS)
AO4430	SOP-8	4430 XXX YYYY	3000

# Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	ymbol Parameter		Unit	
VDS	Drain-Source Voltage	30	V	
Vgs	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous	18	А	
l⊳(70 ℃)	Drain Current-Continuous(Tc=70°C)	8.2	А	
Ідм	Pulsed Drain Current	42	А	
PD	Maximum Power Dissipation	1.5	W	
TJ,TSTG	Operating Junction and Storage Temperature Range	-55 To 150	°C	
Rejc	Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	36	°C <b>/W</b>	







N-Channel MOSFET



## Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

Symbol	ymbol Parameter Conditions		Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =250uA	30			V
∆BV <sub>DSS</sub> /∆T <sub>J</sub>	BVDSS Temperature Coefficient	Reference to 25°C , I <sub>D</sub> =1mA		0.027		V/°C
Rds(on)	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =10V , I <sub>D</sub> =10A		5.5	6.5	mΩ
		V <sub>GS</sub> =4.5V , I <sub>D</sub> =8A		9	12	
V <sub>GS(th)</sub>	Gate Threshold Voltage		1.2	1.5	2.5	V
$ riangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	$V_{GS}=V_{DS}$ , $I_D=250$ uA		-5.8		mV/°C
1	Droin Source Lookage Current	V <sub>DS</sub> =24V , V <sub>GS</sub> =0V , T <sub>J</sub> =25°C			1	
IDSS	Drain-Source Leakage Current	V <sub>DS</sub> =24V , V <sub>GS</sub> =0V , T <sub>J</sub> =55°C			5	uA
Igss	Gate-Source Leakage Current	V <sub>GS</sub> =±20V , V <sub>DS</sub> =0V			±100	nA
gfs	Forward Transconductance	V <sub>DS</sub> =5V , I <sub>D</sub> =10A		5.8		S
Rg	Gate Resistance	V <sub>DS</sub> =0V , V <sub>GS</sub> =0V , f=1MHz		2.2	3.8	Ω
Qg	Total Gate Charge (4.5V)			12.6	17.6	
Qgs	Gate-Source Charge	$V_{DS}$ =15V , $V_{GS}$ =4.5V , $I_D$ =10A		4.2	5.9	nC
Q <sub>gd</sub>	Gate-Drain Charge			5.1	7.1	
T <sub>d(on)</sub>	Turn-On Delay Time			6.2	12.4	
Tr	Rise Time	$V_{DD}$ =15V , $V_{GS}$ =10V , $R_G$ =3.3 $\Omega$		59	106	
T <sub>d(off)</sub>	Turn-Off Delay Time	I <sub>D</sub> =10A		27.6	55	ns
T <sub>f</sub>	Fall Time			8.4	16.8	
Ciss	Input Capacitance			1317	1845	
Coss	Output Capacitance	V <sub>DS</sub> =15V , V <sub>GS</sub> =0V , f=1MHz		163	228.2	pF
Crss	Reverse Transfer Capacitance			131	183.4	

### **Diode Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
ls	Continuous Source Current <sup>1,5</sup>	V V OV Force Current			10.3	Α
I <sub>SM</sub>	Pulsed Source Current <sup>2,5</sup>	$V_G=V_D=0V$ , Force Current			42	А
V <sub>SD</sub>	Diode Forward Voltage <sup>2</sup>	V <sub>GS</sub> =0V , I <sub>S</sub> =1A , T <sub>J</sub> =25°C			1.2	V
trr	Reverse Recovery Time			12.5		nS
Qrr	Reverse Recovery Charge	IF=10A , dl/dt=100A/µs , Tյ=25°C		5		nC

Note :

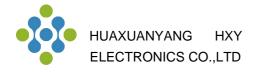
1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.

2.The data tested by pulsed , pulse width  $\,\leq\,$  300us , duty cycle  $\,\leq\,$  2%

3. The EAS data shows Max. rating . The test condition is  $V_{DD}=25V$ ,  $V_{GS}=10V$ , L=0.1mH,  $I_{AS}=35A$ 

4.The power dissipation is limited by 150°C junction temperature

5. The data is theoretically the same as  $I_{\text{D}}$  and  $I_{\text{DM}}$  , in real applications , should be limited by total power dissipation.





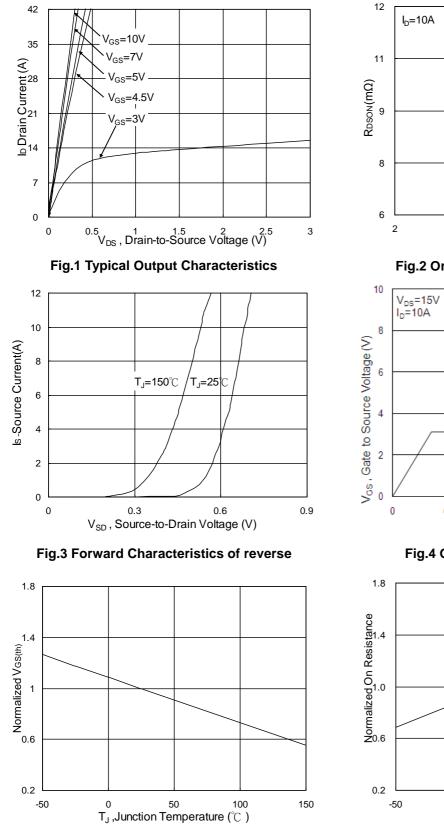


Fig.2 On-Resistance vs. Gate-Source

4

6 V<sub>GS</sub> (V)

8

10

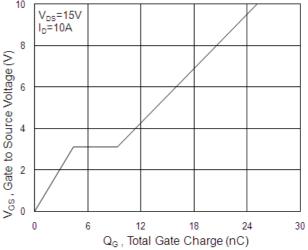


Fig.4 Gate-Charge Characteristics

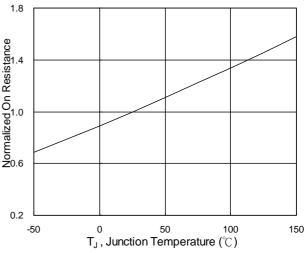
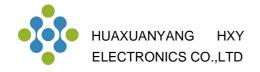


Fig.6 Normalized  $R_{\text{DSON}}$  vs.  $T_{\text{J}}$ 

Fig.5 Normalized V<sub>GS(th)</sub> vs. T<sub>J</sub>



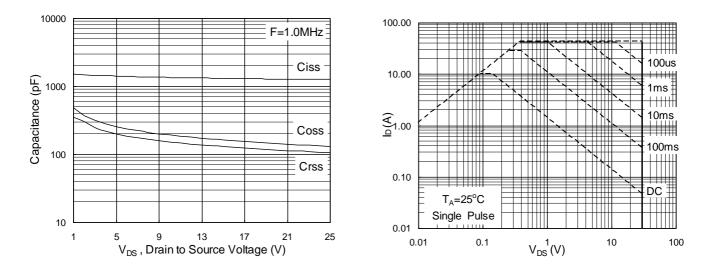
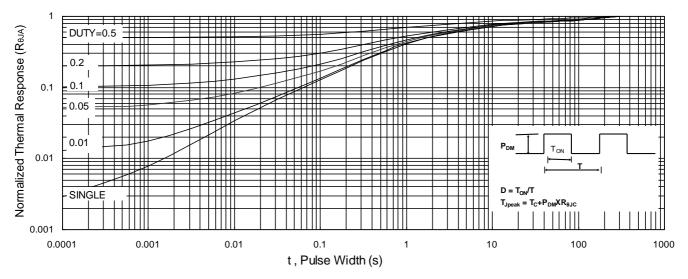


Fig.7 Capacitance

Fig.8 Safe Operating Area





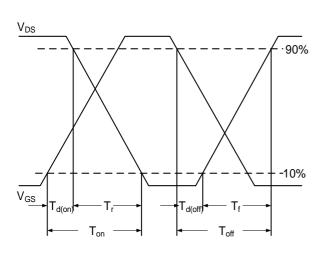


Fig.10 Switching Time Waveform

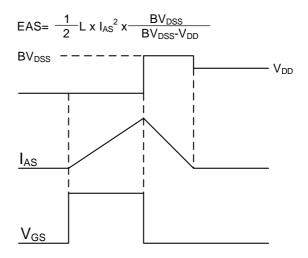
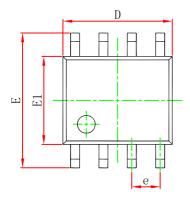
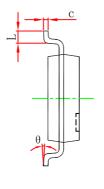


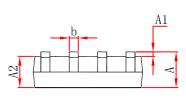
Fig.11 Unclamped Inductive Switching Waveform



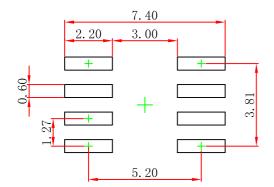
# SOP-8 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.007	0.010	
D	4.800	5.000	0.189	0.197	
e	1.270 (	1.270 (BSC)		(BSC)	
E	5.800	6.200	0.228	0.244	
E1	3.800	4.000	0.150	0.157	
L	0.400	1.270	0.016	0.050	
θ	0 °	8°	0 °	8°	



Note: 1.Controlling dimension: in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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